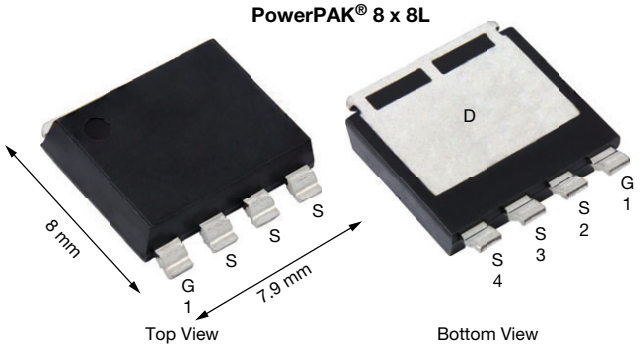
Automotive P-Channel 30 V (D-S) 175 °C MOSFET



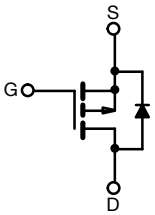
FEATURES

- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Thin 1.6 mm package
- Very low thermal resistance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

RoHS COMPLIANT

HALOGEN FREE



P-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	-30
$R_{DS(on)}$ (Ω) at V_{GS} = -10 V	0.0014
I_D (A)	-280
Configuration	Single
Package	PowerPAK 8 x 8L

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	-30	V
Gate-source voltage		V_{GS}	±20	
Continuous drain current	T_C = 25 °C	I_D	-280	A
	T_C = 125 °C		-280	
Continuous source current (diode conduction)		I_S	545	
Pulsed drain current [b]		I_{DM}	-280	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	63	
Single pulse avalanche energy		E_{AS}	198	mJ
Maximum power dissipation	T_C = 25 °C	P_D	600	W
	T_C = 125 °C		200	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) [d]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount [c]	R_{thJA}	44	°C/W
Junction-to-case (drain)		R_{thJC}	0.25	

Notes

a. Package limited
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %
c. When mounted on 1" square PCB (FR4 material)
d. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

For technical questions, contact: automostechsupport@vishay.com

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SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0, I_D = 250 µA		-30	-	-	V
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		-1.5	-2	-2.5	
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{GS} = 0 V	V_{DS} = -30 V	-	-	1	µA
		V_{GS} = 0 V	V_{DS} = -30 V, T_J = 125 °C	-	-	200	
		V_{GS} = 0 V	V_{DS} = -30 V, T_J = 175 °C	-	-	330	
On-state drain current [a]	$I_{D(on)}$	V_{GS} = -10 V		-100	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = -4.5 V	V_{DS} ≥ -5 V, I_D = -8 A	-	0.0015	0.0022	Ω
		V_{GS} = -10 V	I_D = -10 A	-	0.0010	0.0014	
		V_{GS} = -10 V	I_D = -10 A, T_J = 125 °C	-	-	0.0019	
		V_{GS} = -10 V	I_D = -10 A, T_J = 175 °C	-	-	0.0022	
Forward transconductance [b]	g_{fs}	V_{DS} = -15 V, I_D = -50 A		-	180	-	S
Dynamic [b]							
Input capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = 15 V, f = 1 MHz	-	23 588	33 050	pF
Output capacitance	C_{oss}			-	2443	3420	
Reverse transfer capacitance	C_{rss}			-	2267	3174	
Total gate charge [c]	Q_g	V_{GS} = 10 V	V_{DS} = -15 V, I_D = -30 A	-	487	731	nC
Gate-source charge [c]	Q_{gs}			-	86	-	
Gate-drain charge [c]	Q_{gd}			-	82	-	
Gate resistance	R_g	f = 1 MHz		1	2.1	3.2	Ω
Turn-on delay time [c]	$t_{d(on)}$	V_{DD} = -15 V, R_L = 0.5 Ω I_D ≅ -30 A, V_{GEN} = -10 V, R_g = 1 Ω		-	20	30	ns
Rise time [c]	t_r			-	30	45	
Turn-off delay time [c]	$t_{d(off)}$			-	194	291	
Fall time [c]	t_f			-	78	117	
Source-Drain Diode Ratings and Characteristics [b]							
Reverse recovery time	t_a	V_{DD} = -24 V, I_{FM} = -20 A, di/dt = 100 A/µs		20	-	-	ns
	t_b			24	-	-	
	t_{rr}			-	43	86	
Reverse recovery charge	Q_{rr}			-	45	90	nC
Reverse recovery current	I_{RM}			-	-	1.9	A
Pulsed current [a]	I_{SM}			-	-	1100	A
Forward voltage	V_{SD}	I_F = -50 A, V_{GS} = 0		-	-0.8	-1.1	V

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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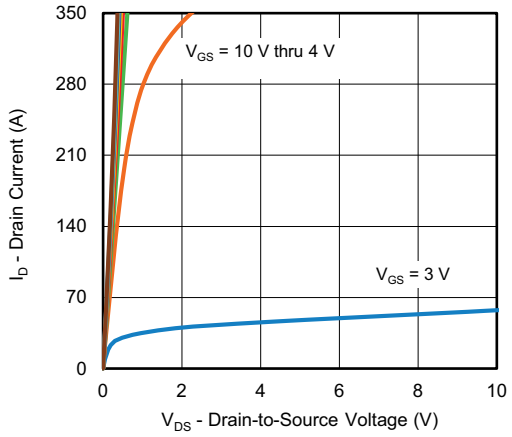
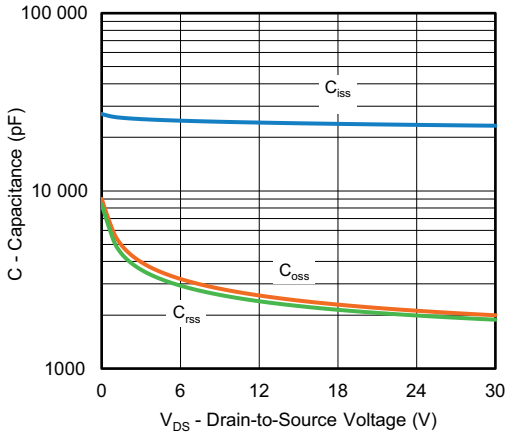
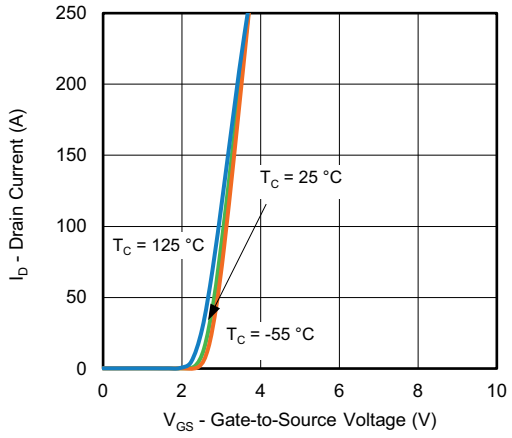
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



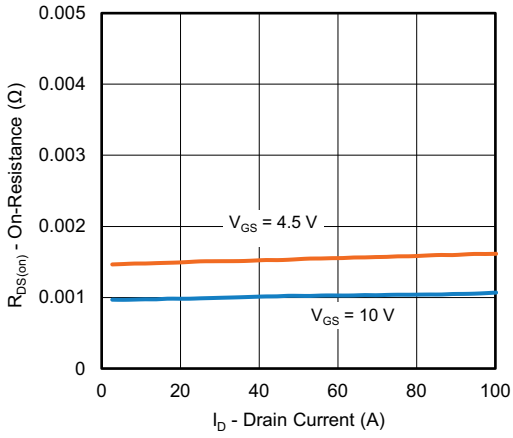
Output Characteristics



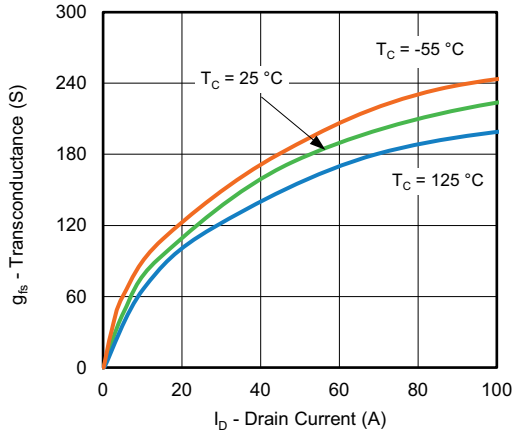
Capacitance



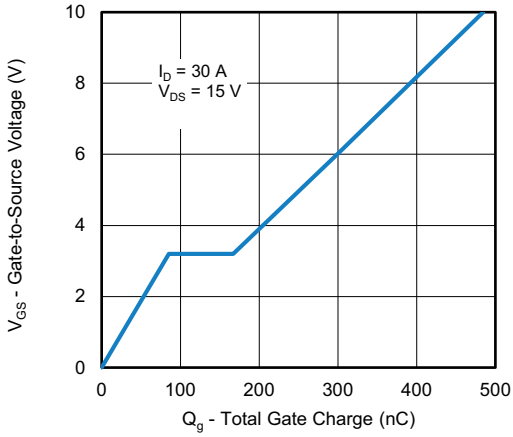
Transfer Characteristics



On-Resistance vs. Drain Current



Transconductance



Gate Charge

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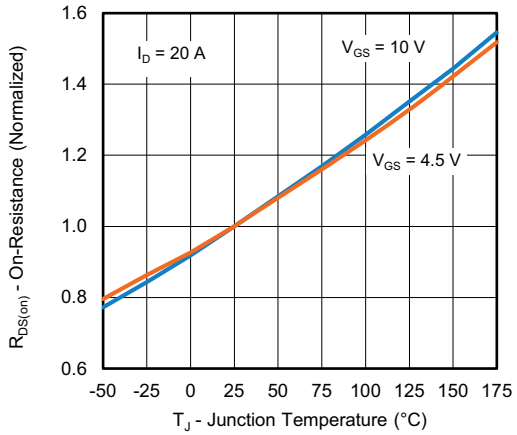
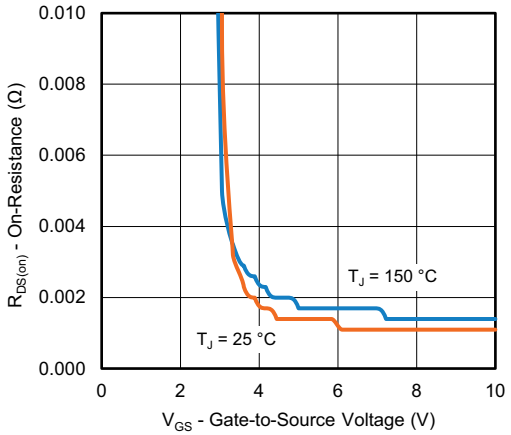
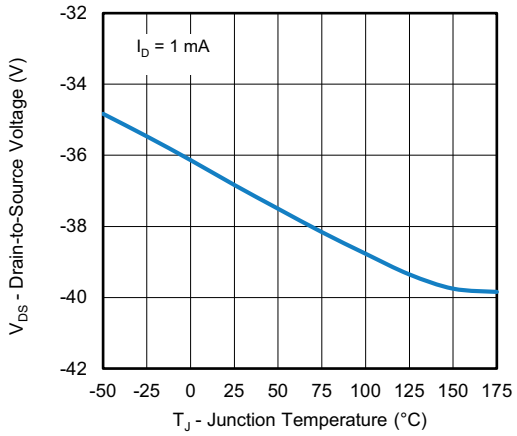


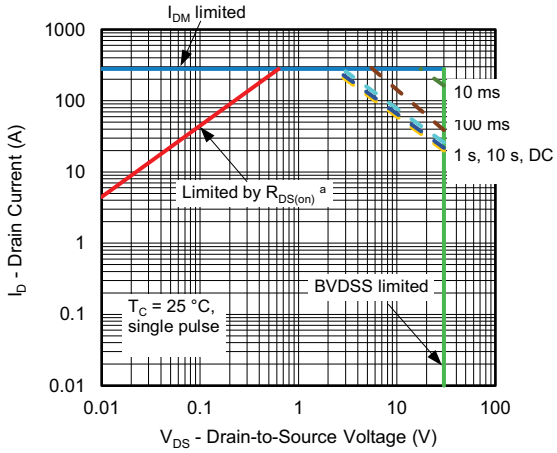
On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



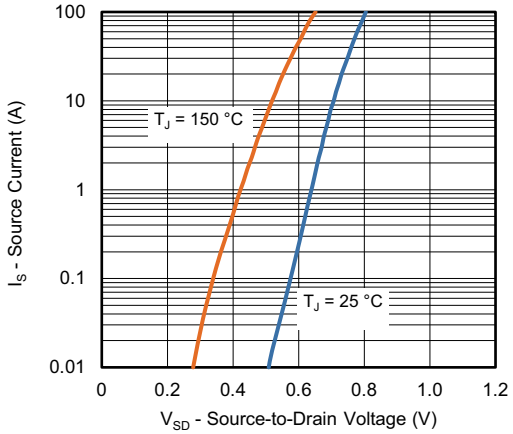
Drain Source Breakdown vs. Junction Temperature



Safe Operating Area

Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



Source Drain Diode Forward Voltage

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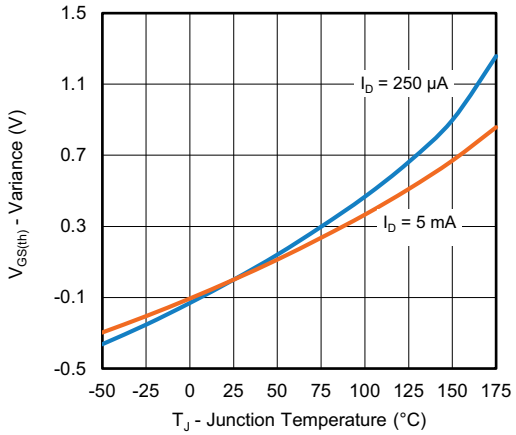
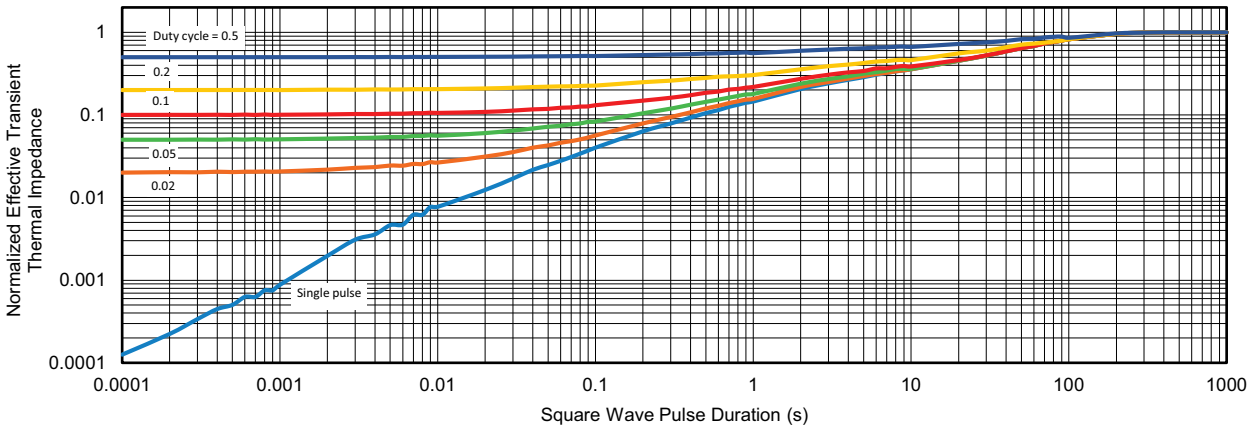
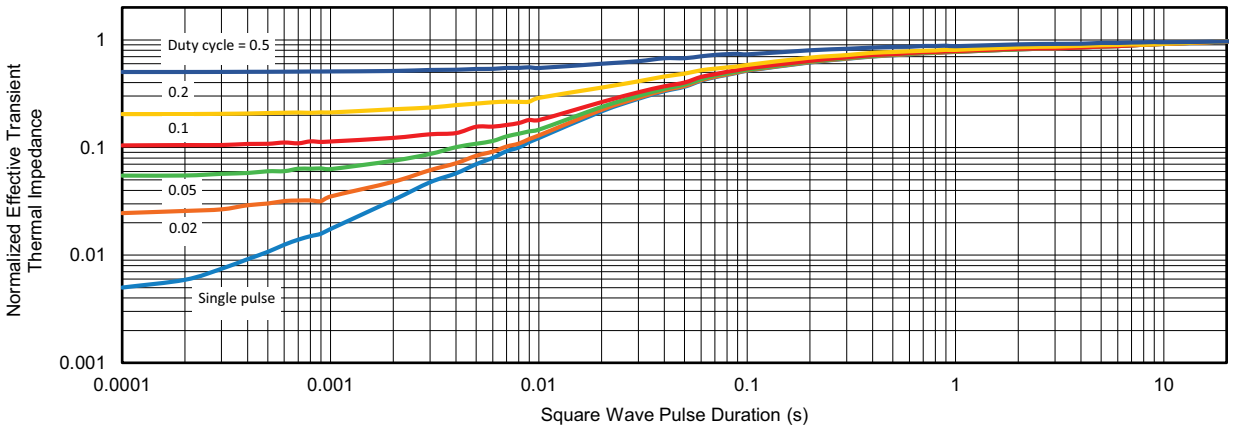
THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Threshold Voltage



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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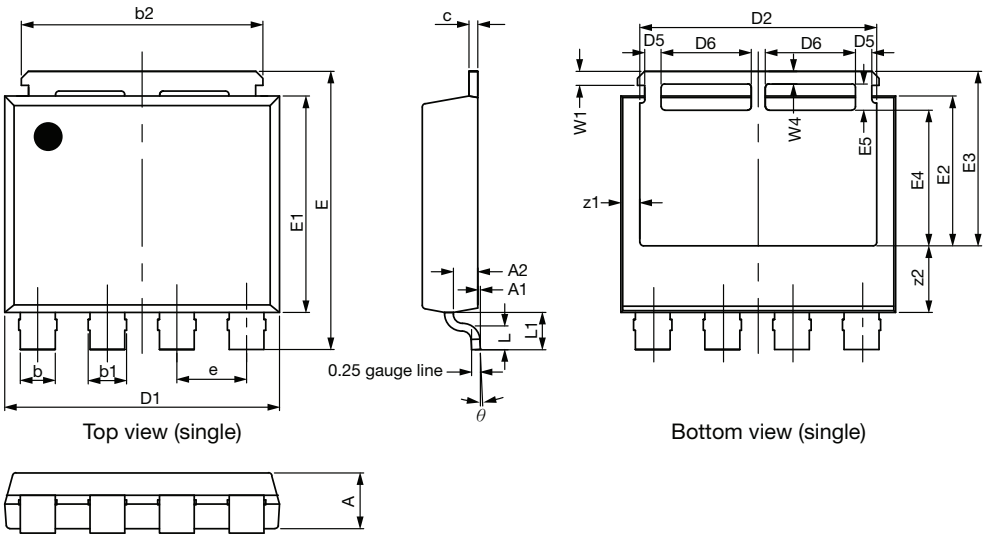
PowerPAK® 8 x 8L BWL Case Outline 2



Top view (single)

Bottom view (single)

DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.50	1.60	1.70	0.059	0.063	0.067
A1	0.00	-	0.127	0.000	-	0.005
A2	0.655	0.705	0.755	0.026	0.028	0.030
b	0.92	1.00	1.08	0.036	0.039	0.043
b1	1.02	1.10	1.18	0.040	0.043	0.046
b2	6.84	6.94	7.04	0.269	0.273	0.277
c	0.20	0.25	0.30	0.008	0.010	0.012
D1	7.80	7.90	8.00	0.307	0.311	0.315
D2	6.70	6.80	6.90	0.264	0.268	0.272
D5	0.37	0.47	0.57	0.015	0.019	0.022
D6	2.49	2.59	2.69	0.098	0.102	0.106
e	1.97	2.00	2.03	0.078	0.079	0.080
E	7.90	8.00	8.10	0.311	0.315	0.319
E1	6.12	6.22	6.32	0.241	0.245	0.249
E2	4.21	4.31	4.41	0.166	0.170	0.174
E3	4.92	5.02	5.12	0.194	0.198	0.202
E4	3.80	3.90	4.00	0.150	0.154	0.157
E5	0.65	0.75	0.85	0.026	0.030	0.033
L	0.61	0.68	0.75	0.024	0.027	0.030
L1	1.00	1.07	1.15	0.039	0.042	0.045
W1	0.30	0.40	0.50	0.012	0.016	0.020
W4	0.32	0.37	0.42	0.013	0.015	0.017
z1	0.45	0.55	0.65	0.018	0.022	0.026
z2	1.81	1.91	2.01	0.071	0.075	0.079
θ	0°	-	5°	0°	-	5°
ECN: S19-0643-Rev. B, 05-Aug-2019 DWG: 6073						

Note

- Millimeter will govern

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